



Data Sheet

FDS6986AS Trans MOSFET N-CH 30V 6.5A/7.9A 8Pin SOIC T/R RoHS

Manufacturers ON Semiconductor, LLC

Package/Case SOP-8

Product Type Transistors

RoHS Green

Lifecycle



Images are for reference only

Please submit RFQ for FDS6986AS or Email to us: sales@ovaga.com We will contact you in 12 hours.



## **General Description**

The FDS6986AS is designed to replace two single SO-8 MOSFETs and Schottky diode in synchronous DC:DC power supplies that provide various peripheral voltages for notebook computers and other battery powered electronic devices. FDS6986AS contains two unique 30V, N-channel, logic level, PowerTrenchMOSFETs designed to maximize power conversion efficiency. The high-side switch (Q1) is designed with specific emphasis on reducing switching losses while the lowside switch (Q2) is optimized to reduce conductionlosses. Q2 also includes an integrated Schottky diode using Fairchild's monolithic SyncFET technology.

Features Application

Q2Optimized to minimize conduction lossesIncludes SyncFET Schottky body diode7.9A, 30VMax. = 10 VMax. = 4.5 V ONSEMI

Q1 Optimized for low switching losses A, VMax. = 10 VMax. = 4.5 VLow gate charge (10 nC typical)



## **Related Products**



**FDC645N** 

ON Semiconductor, LLC SSOT-6



**FDC6305N** 

ON Semiconductor, LLC SSOT-6



**FDD8647L** 

ON Semiconductor, LLC TO-252-3



FDD5N50NZTM

ON Semiconductor, LLC TO-252



FDC637BNZ

ON Semiconductor, LLC SSOT-6



**FDC602P** 

ON Semiconductor, LLC SOT163



FDB070AN06A0

ON Semiconductor, LLC TO-263



**FDD3670** 

ON Semiconductor, LLC TO-252AA